

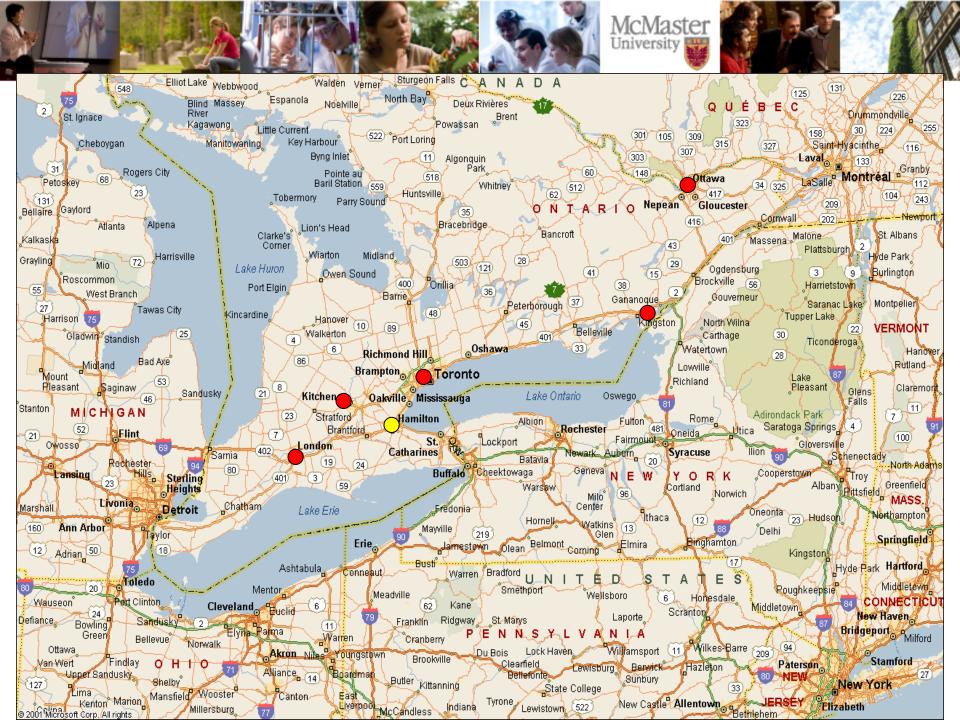
Nanoscience and Nanotechnology at McMaster University

A Model for an Interdisciplinary Approach

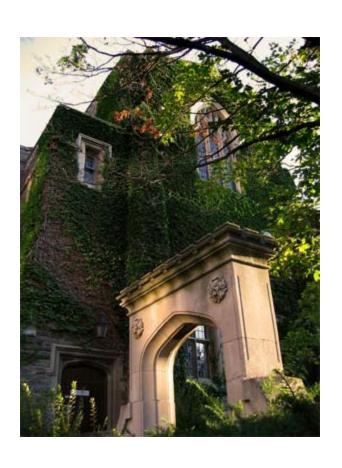
Arizona Nanotechnology Symposium: Small is Big











McMaster University

- Established in 1887
- 65 km SW of Toronto / 70 km SE of Waterloo
- 21,000+ undergraduate and graduate students
- 1,170+ full-time faculty (96% with PhD)
- 6 Faculties health sciences, engineering, business, humanities, science, social science
- 140 undergraduate degree programs
- Students & faculty from 70+ countries
- 40+ international exchange agreements
- Among the Top 10 best places to work in academia (The Scientist)



M. I. N. I.

MCMASTER INITIATIVE in NANO INNOVATION



CEDT

Centre for Emerging Device Technologies

Devices Systems

Micro- and Nanosystems Laboratory (CFI/ORF RI 2007)

Materials



Brockhouse Institute for Materials Research





FACILITIES

Materials Growth

- •Molecular Beam Epitaxy
 - AlInGaAsPSb(N)
- •ICP-PECVD with in-situ Ellipsometry
 - **ECR-PECVD**
 - **RF-Magnetron Sputtering**
 - Laser Ablation
- Pulsed Laser Deposition

Photonic and Optoelectronics Integration and Packaging

Materials Characterization

- **Photoluminescence**
- **Electroluminescence**
- **Electron Microscopy**
 - **X-ray Diffraction**
 - •Hall Effect
- **Positron Annihilation**
 - **Spectroscopic and**
- **Scanning Ellipsometry**
 - Thin Film Stress
 Measurement
- **Surface Profilometry**
 - ScanningPhotoluminescenceand Reflectance
 - Nuclear Magnetic
 Resonance

Device Fabrication

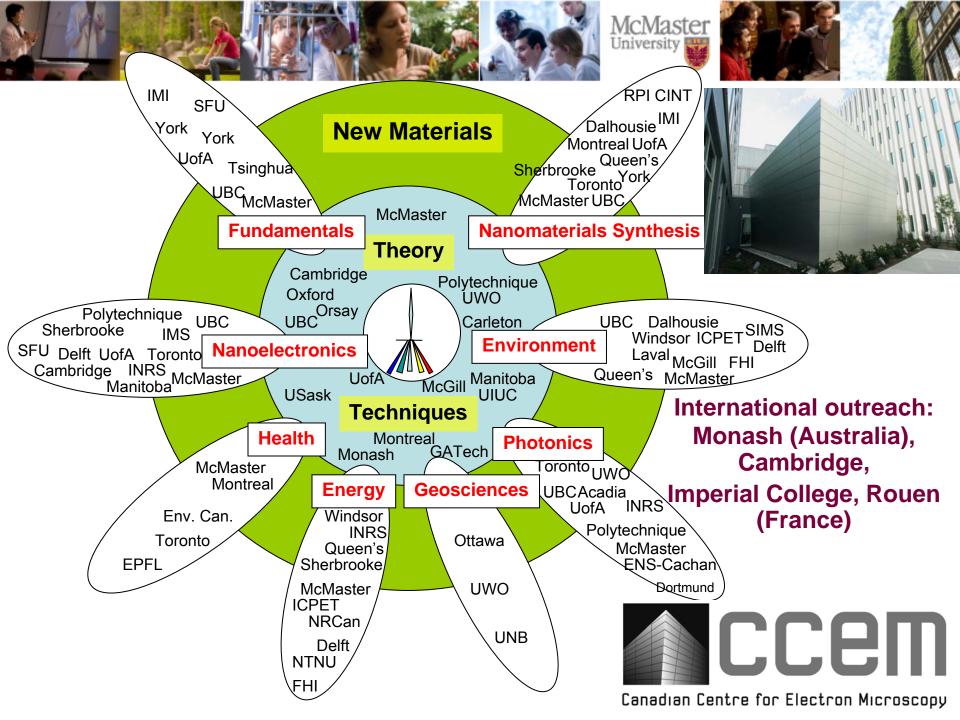
Mask Design
Device Modelling

Clean Room Facilities:
Photo- and e-beam
lithography
FIB
Metallization
Reactive Ion Etching

Device Testing

Holographic Gratings

High-speed/highfrequency Reliability Studies Bio-electromagnetics "Quiet" Environments





The Canadian Centre for Electron Microscopy





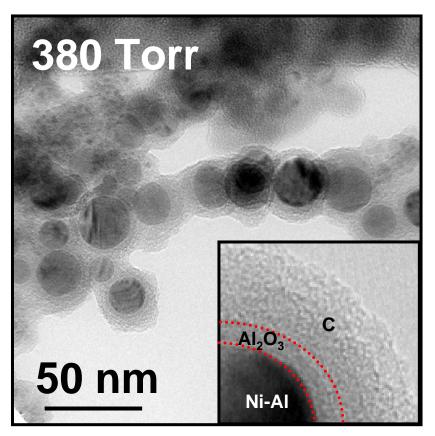
2 FEI Titans:

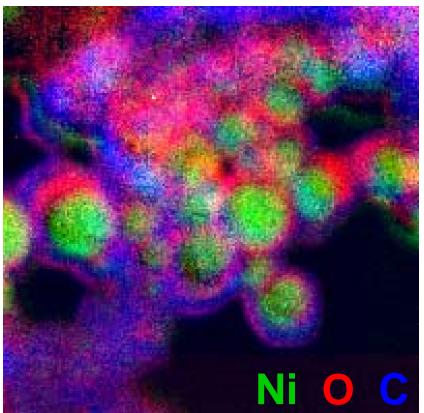
- 1) double correctors and monochromator
- 2) image corrector and monochromator, laser

JEOL 2010F, STEM HB601 Cryo, JEOL 7000F SEM, CM12, Zeiss NVision FIB/SEM

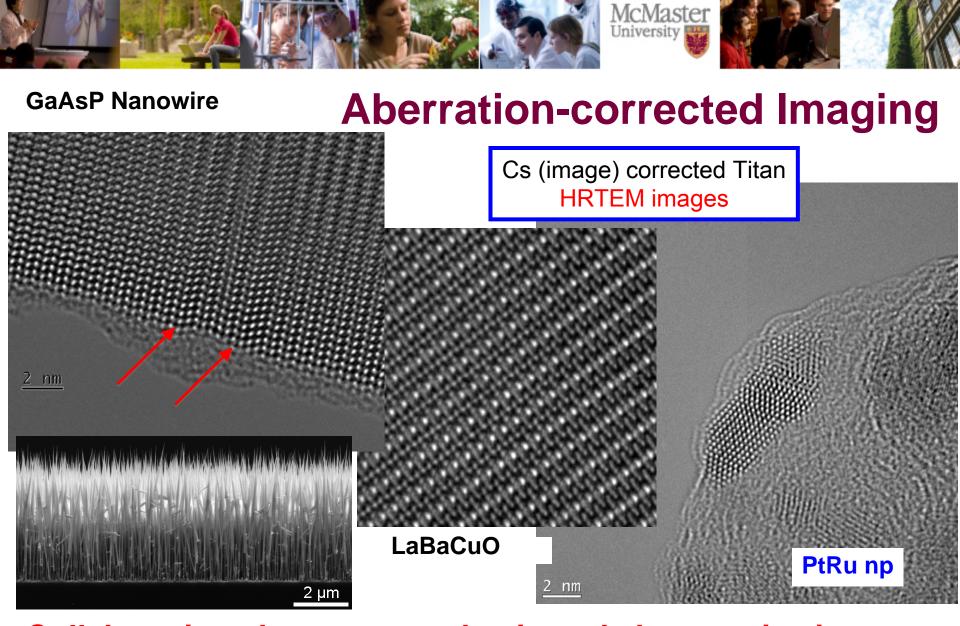


Elemental Analysis of Nanoscale Structures





G. Botton's Group: N. Braidy, PhD student, C.Andrei, PDF Collaboration with R. Hughes and J. Preston, PLD Laboratory, BIMR



Collaborations between synthesis and characterization experts



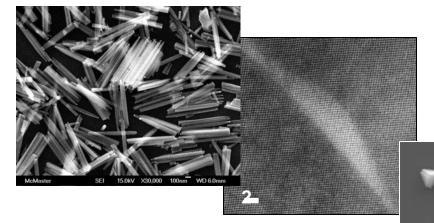


- □ Functionalized Carbon Nanotubes
- □ Silicon Nanostructures
- ☐ III-V and II-VI Quantum Structures



McMaster





NANOSTRUCTURED DEVICES

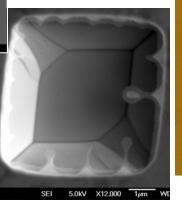
□ Wireless Sensors **□** Superlattice Photodetectors □ Nanoelectronics-based Bio-imaging □ Nanowire-based Photovoltaics

□ Silicon Photonic Circuits

MEMS and BIO-MEMS



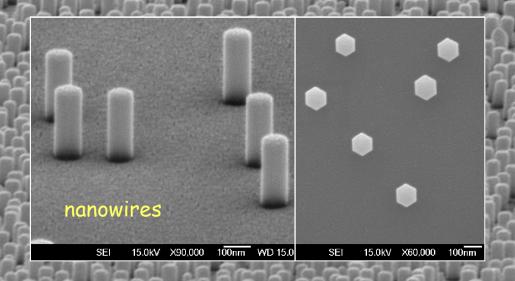
- □ Crystallization□ Confinement
- □ Self-assembly and Pattern Formation

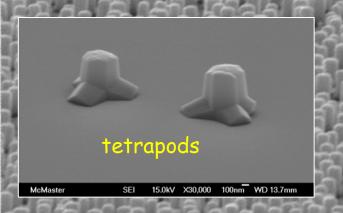


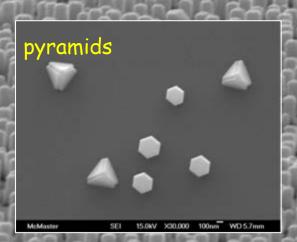


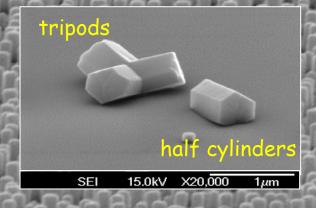
CdTe Nanowire Structures









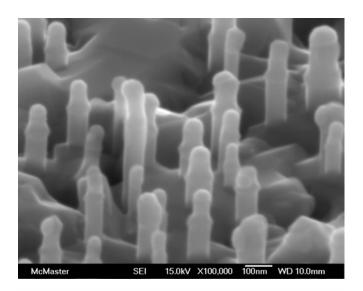


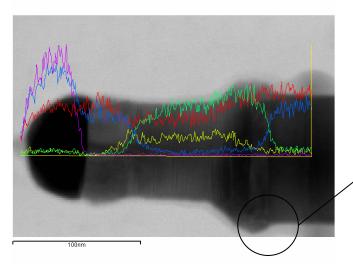
J. Preston, R. Hughes, P.Mascher, S. Neretina, CEDT and BIMR

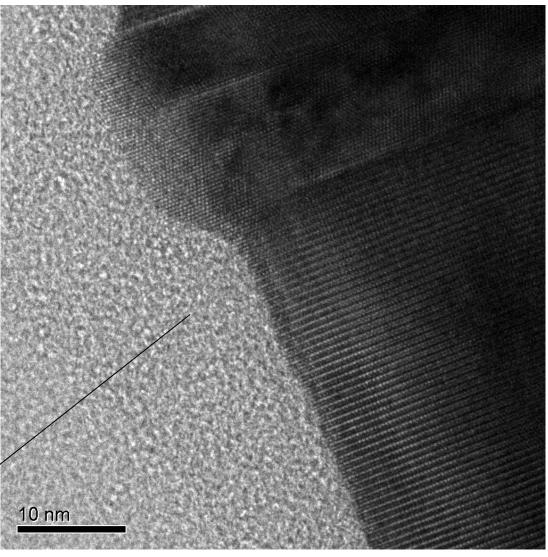


Nanowire structures: InP/InGaAs/InP

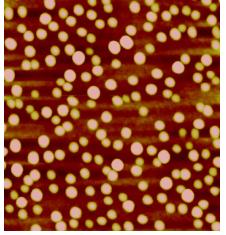
R.R. LaPierre G. Botton



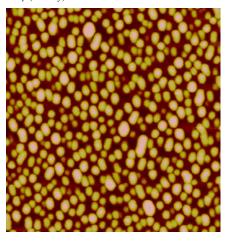




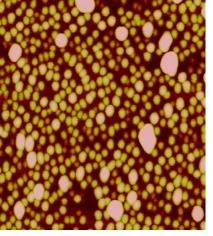




D (Diameter) = 22.1 ± 0.15 nm H (Height) = 10.03 ± 0.70 nm ρ (Density) = 8.04×10^{10} cm⁻²



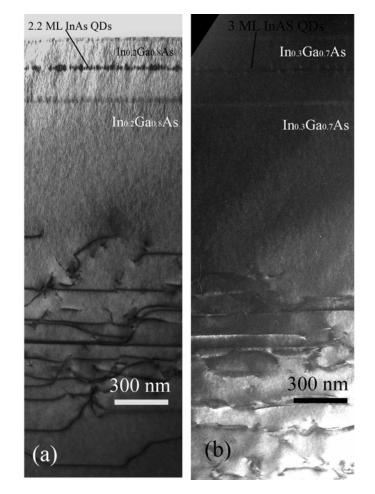
$$\begin{split} D &= 19.34 \pm 0.10 \text{ nm} \\ H &= 9.23 \pm 0.65 \text{ nm} \\ \rho &= 1.87 \times 10^{11} \text{ cm}^{-2} \end{split}$$



D = 16.36 ± 0.08 nm H = 9.14 ± 0.65 nm $\rho = 1.30 \times 10^{11}$ cm⁻²

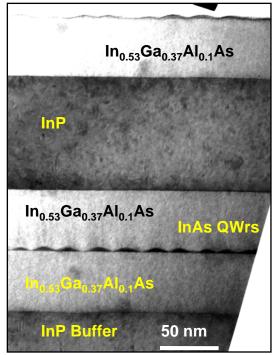
InAs Quantum Dots (GS-MBE)

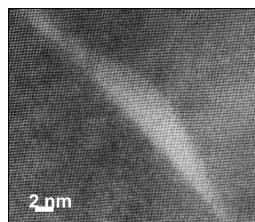
D.A. Thompson and S. Tavakoli



Room temperature PL from QDots: Growth on meta-morphic layers

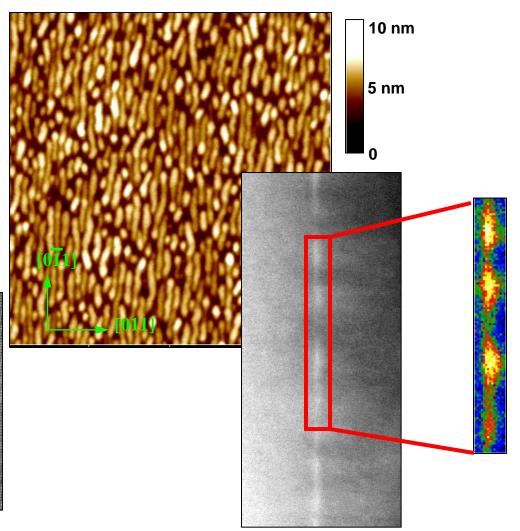


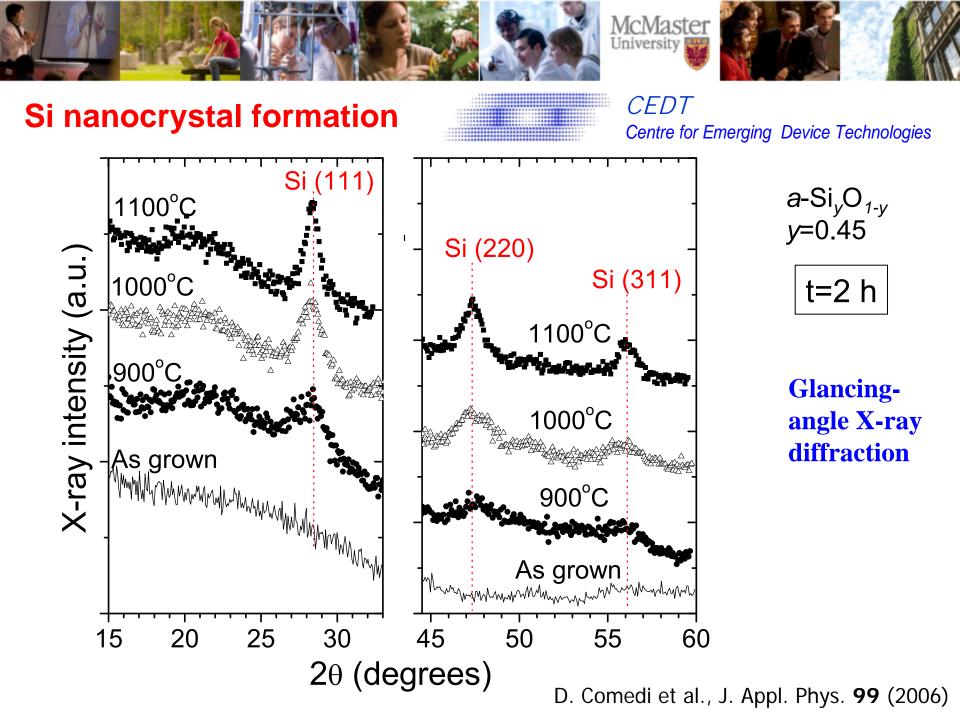




InAs Quantum Wires (GS-MBE)

D.A. Thompson, K. Cui and G. Botton







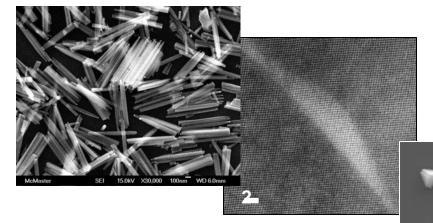


- □ Functionalized Carbon Nanotubes
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NANOSTRUCTURED DEVICES

□ Wireless Sensors **□** Superlattice Photodetectors

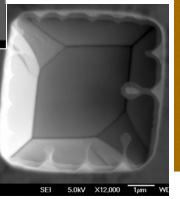
□ Nanoelectronics-based Bio-imaging □ Nanowire-based Photovoltaics

□ Silicon Photonic Circuits



- POLYMER NANOTECHNOLOGY
 - □ Crystallization□ Confinement

 - □ Self-assembly and Pattern Formation







CEDT
Centre for Emerging Device Technologies



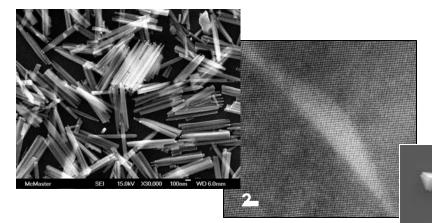


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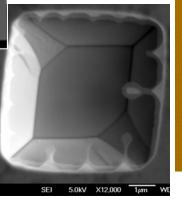
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POLYMER NANOTECHNOLOGY

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250 nm

These are droplets of PEO on a substrate imaged with AFM. The black droplets have not yet crystallised (i.e. they are liquid), the striped droplets are crystalline and show their lamellae. Note that the small droplet has just 10 molecules!

McMaster University

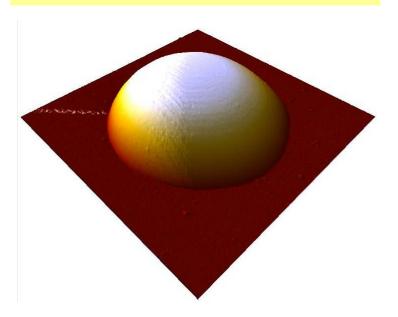
Kari Dalnoki-Veress

only ~10 chains (370 kg/mol)!!!



Droplets in an anisotropic liquid

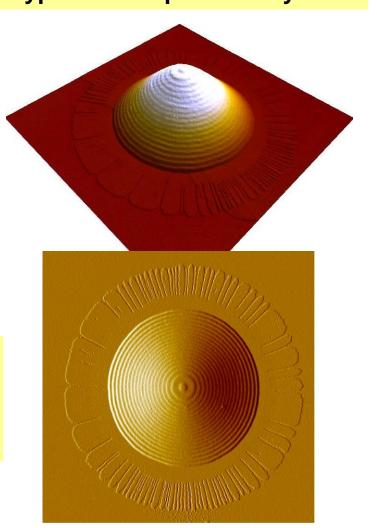
Expected spherical cap



These droplets can be used to make lenses that have unique optical properties because they are hyperbolic in shape. They can also be used as building blocks in nano-devices

Kari Dalnoki-Veress

Hyperbolic cap that is layered!





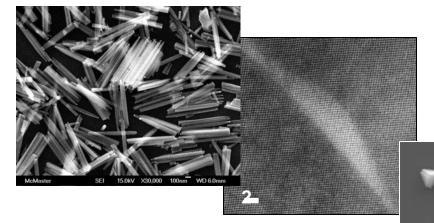


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McMaster





☐ NANOSTRUCTURED DEVICES

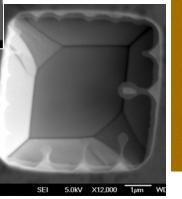
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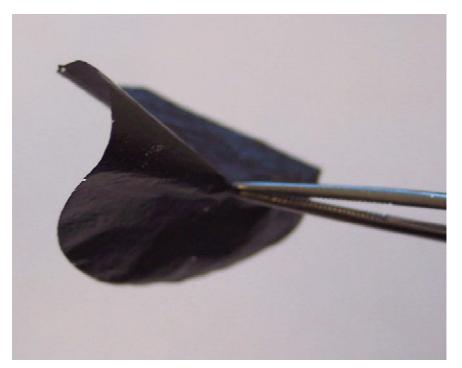


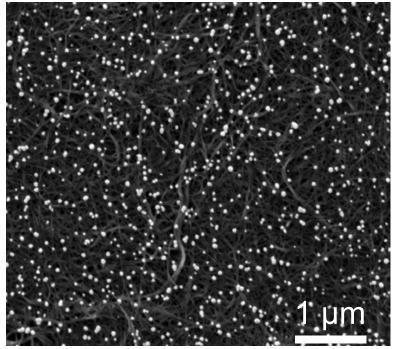




Ray LaPierre (Engineering Physics) and Alex Adronov (Chemistry)

» ADRONOV FABRICATES FLEXIBLE, CONDUCTIVE FILMS OF STACKED SWNTS, FUNCTIONALIZED WITH AU NANOPARTICLES





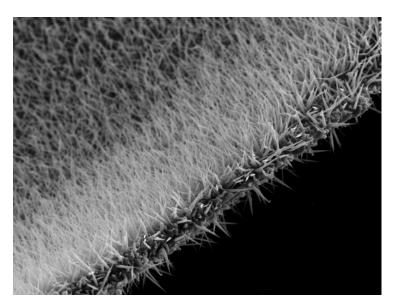








» THE AU NANOPARTICLES ACT AS SEEDS FOR SEMICONDUCTOR NANOWIRE GROWTH. LAPIERRE GROWS III-V NANOWIRES ON ADRONOV'S CNT FILMS FOR PV APPLICATIONS





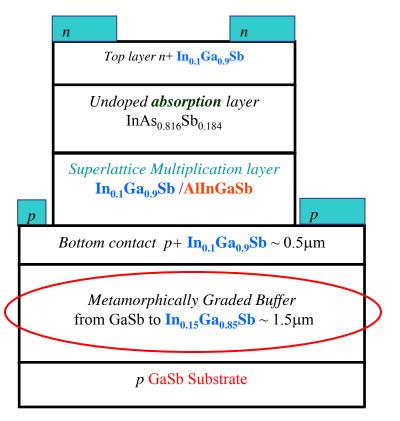




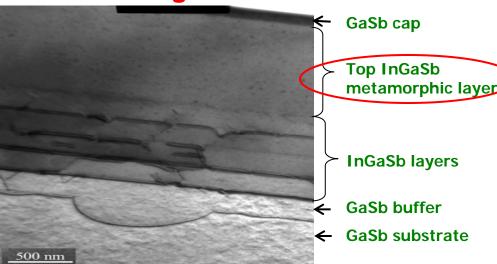
CEDT
Centre for Emerging Device Technologies



- Antimonide materials
- Mid Infrared lasers/detectors for
 - Biomedical applications
 - Defense and security applications
 - Next generation non-silica fibers

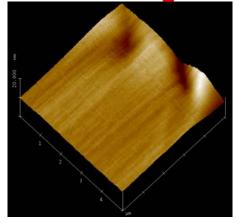


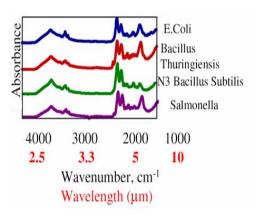
TEM images

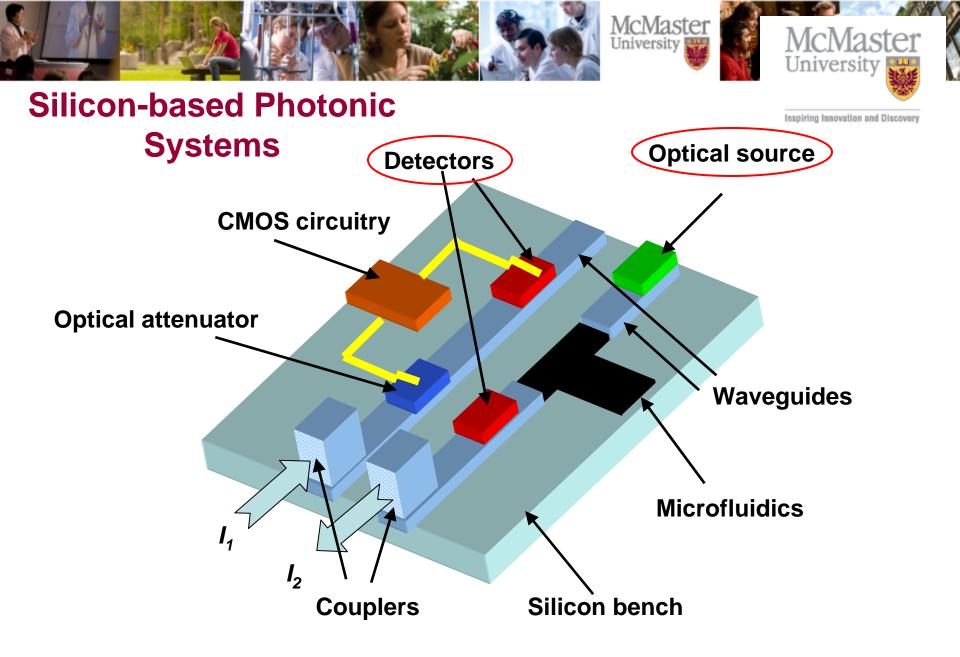


McMaster
University

AFM image



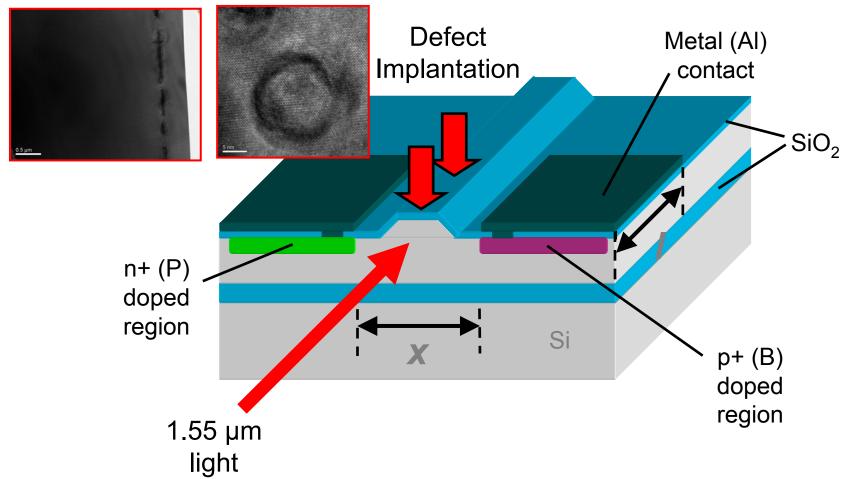




P. Jessop, A. Knights, P. Mascher (McMaster), G. Tarr (Carleton), S. Janz (NRC)



Device Design & Fabrication

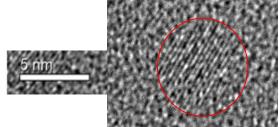


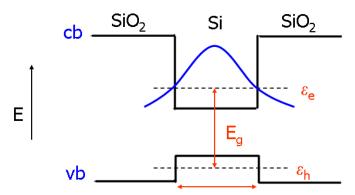
Bradley, Jessop, and Knights, APL 86, 241103 (2005).



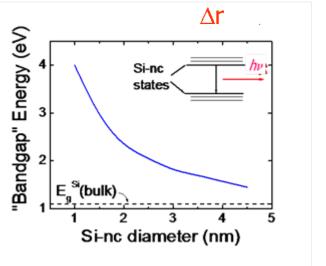
Silicon Photonics – A Nano Solution?

- Silicon on the nanoscale (Si-ncs)
 - Nanocrystals
 - Amorphous nanoclusters
- Quantum confinement
 - Localization of electrons and holes
 - Bandgap widening
 - Relaxation of k-selection rules
 - Uncertainty principle
 - 'quasi-direct' recombination
- Inter-bandgap electronic states
 - □ Limit observed emission range
 - Si=O double bond
 - Wolkin et al. PRL 82, 197 (1999)



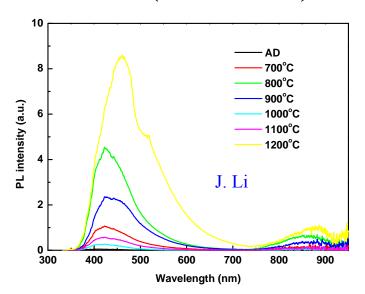


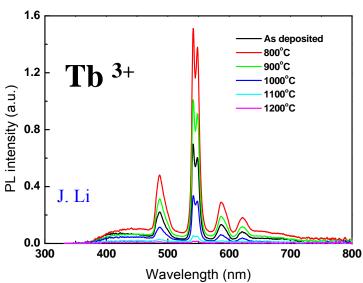
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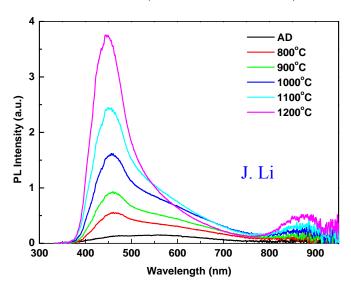


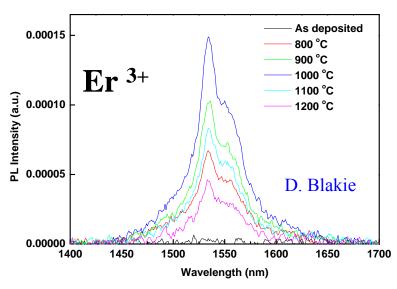






Eu ²⁺ (and Si-ncs)

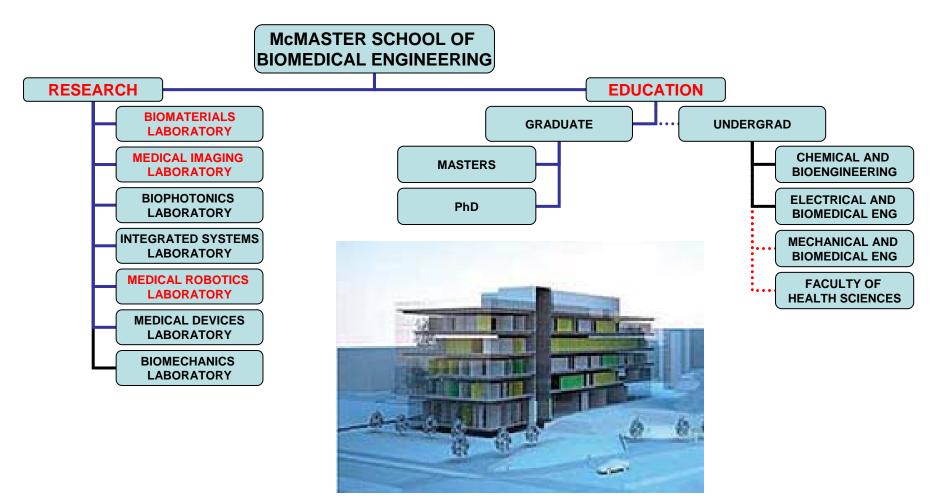


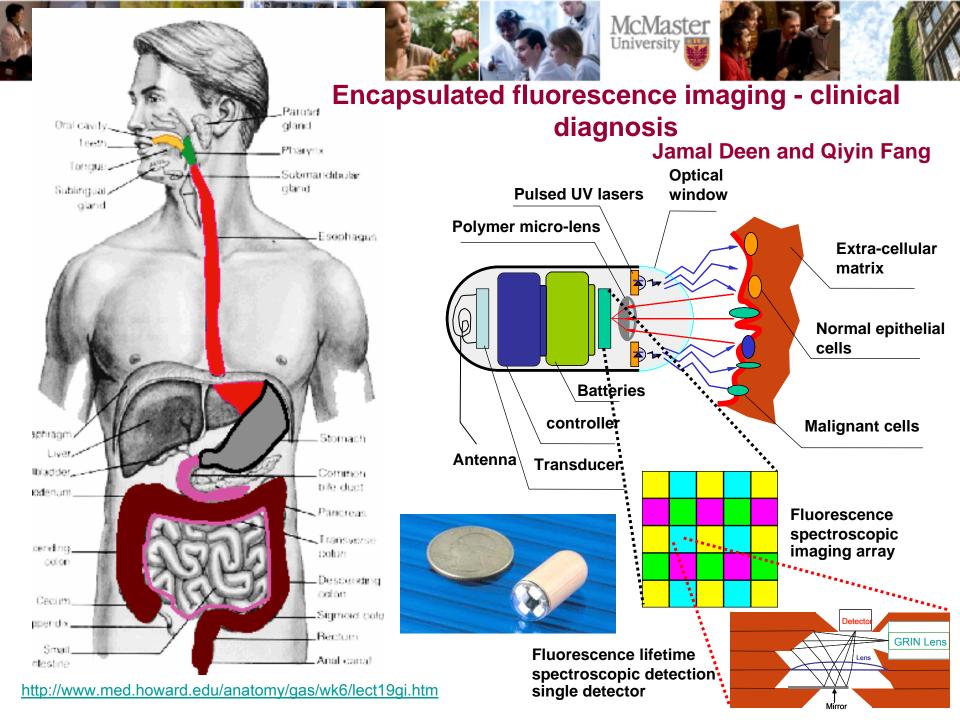




McMaster School of Biomedical Engineering -

An Equal Partnership of Engineering and Health Sciences



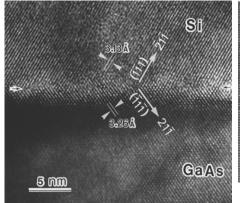


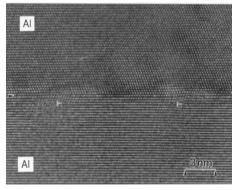


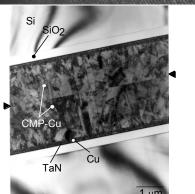
Bonding and Interconnect System

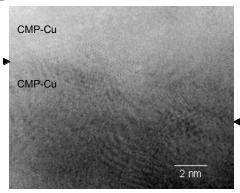
Atom and ion beam cleaning and bonding cluster Scanning electron Surface Load lock chamber with microscope with electron analyzing transportation tool beam lithography cluster capability Plasma cleaning Door and bonding NBIS's Features: cluster Alignment accuracy: +/- 0.5 µm Surface activation: Low vacuum, UHV Sample accommodation: as small as 1 sq. mm. Bonding environments: Low vacuum, UHV N2 gas, Air Bonding materials: Ultra-thin metal, semiconductor, ceramic and piezoelectric material

An integration facility that will be second to none in its capabilities



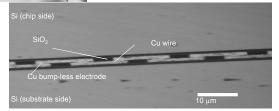






Key advantages of surface activated bonding

- No requirement of external pressure, adhesive or heating
- Sub-μm alignment and placement of components
- · Two- and three-dimensional integration of dissimilar materials













Contact Information



Rafael Kleiman, Director

Centre for Emerging Device Technologies



Canadian Centre for Electron Microscopy

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Director
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Brockhouse Institute for Materials Research

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Micro- and Nano-systems

Laboratorymal Deen, Director jamal@mcmaster.ca



Peter Mascher, Program Director mascher@mcmaster.ca

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MCMASTER INITIATIVE in NANO INNOVATION

http://www.eng.mcmaster.ca/~wwwmini/















Nano and Giga Challenges 14th Canadian Semiconductor in Electronics, Technology Conference
Photonics and Renewable Energy

Symposium and Summer School (Tutorial Lectures) Hamilton, Ontario, Canada, August 10 - 14, 2009

For further information and registration visit our web site at:

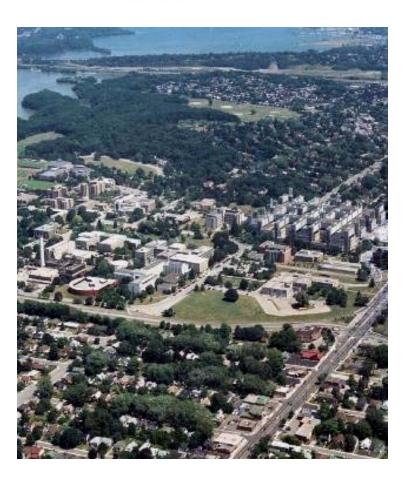
http://asdn.net/ngc2009/ or http://cstc2009.mcmaster.ca

or contact

organizers@asdn.net







McMaster University – Research Accolades

- Ranked Canada's most innovative "medical doctoral" university eight times in the last 11 years in *Maclean's* annual ranking of universities
- Ranked #1 in Canada for Research Intensity (\$ per full-time faculty) Canada's Research University of the Year 2004 (ResearchInfosource)
- Ranked 6th in Canada's Top 50 Research Universities with \$308.3 million in sponsored research income
- Ranked among the top 100 universities in the world (China's Shanghai Jiao Tong University annual ranking)
- 1 of only 7 Canadian universities ranked in the top 200 universities in the world by *The Times Higher Education Supplement* (2006)









McMaster University

Strategic Research Areas

- Molecular Biology
- Information Technology
- Globalization and the Human Condition
- Science-based Innovation in Manufacturing and Materials
- Work and Society
- Integrated Health Research

Faculty of Engineering

Research Priority Areas

- Information Technology
- Biomedical Engineering
- Materials and Manufacturing
- Sustainable Energy Systems
- Micro- and Nano-systems





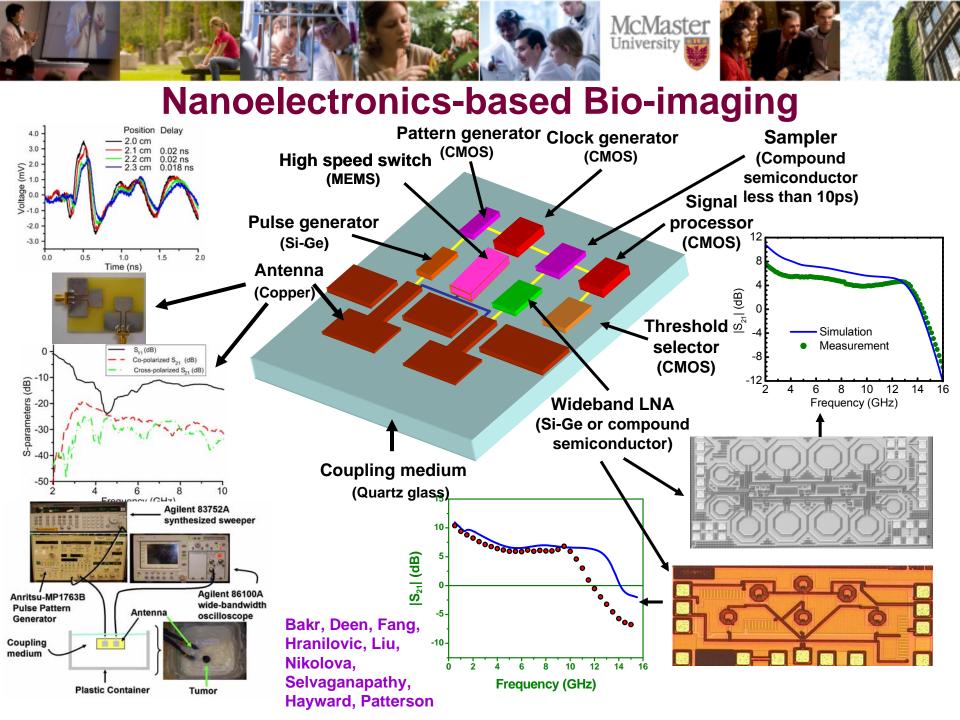


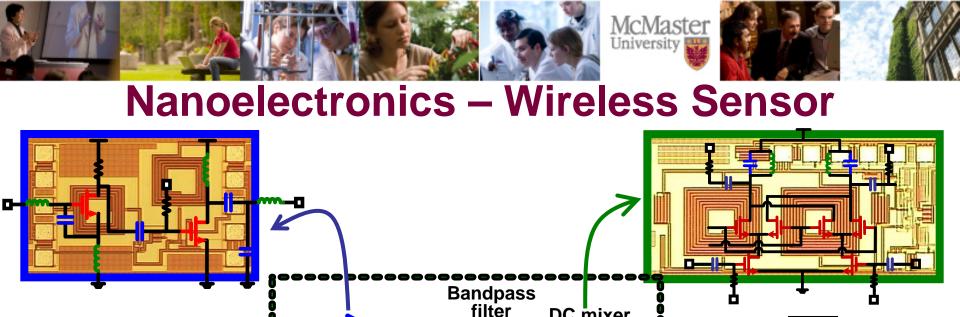
McMaster Innovation Park

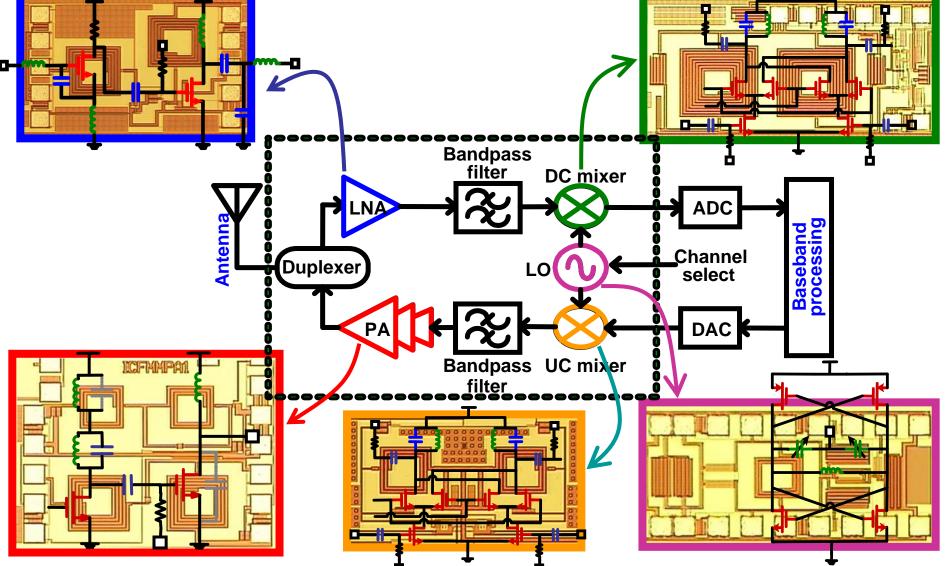
- 37-acres of brownfields and warehouses being developed into a premiere research park
- Future home of CANMET Materials Technology Laboratory and General Motors of Canada's Centre for Corrosion Engineering Research

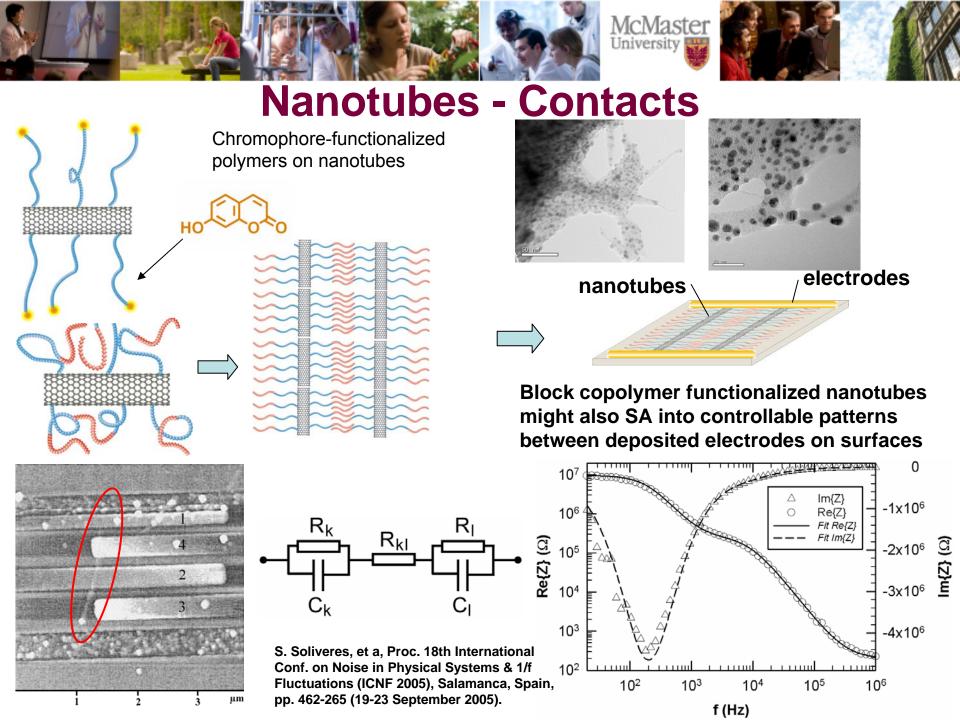








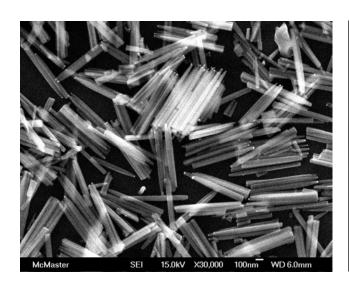




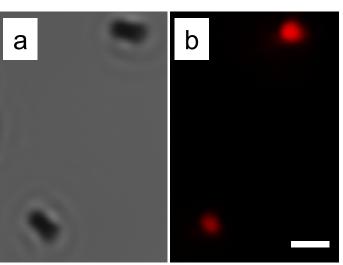


Collaboration between Ray LaPierre (Engineering Physics), Cecile Fradin (Physics), and Bhagwati Gupta (Department of Biology)

» LAPIERRE GROWS LIGHT EMITTING NANOWIRES. FRADIN AND GUPTA USE NANOWIRES FOR CELLULAR STUDIES.



SEM image showing ensemble of AlGaAs nanowires.



Microscopy (left) and PL image (right) of nanowires. Nanowires emit in the visible region (700 nm) at room temperature. Scale bar is 1 μ m.

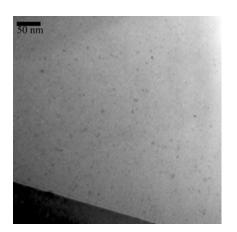


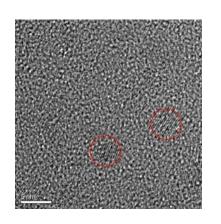
Nanowires are injected into nematode for cellular and toxicological studies.

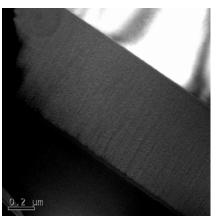


Si-ncs: Structure

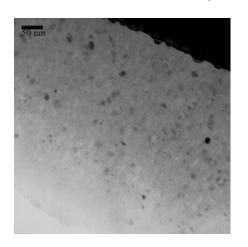
□ 39% Si, annealed at 1100 °C (BFTEM, HRTEM, EFTEM)

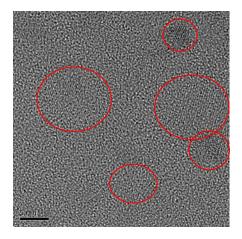






■ 42 % Si, annealed at 1100 °C (BFTEM) and 1200 °C (HRTEM)





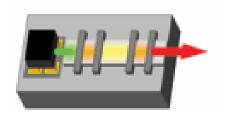
T.R. Roschuk et al., ECS Transactions 6, 2007

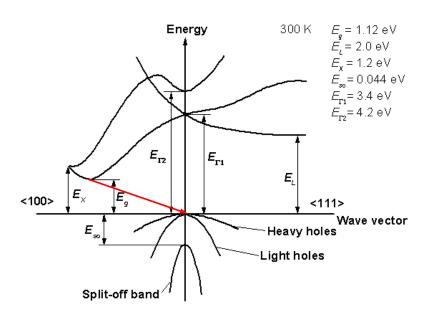


Silicon Photonics – The Giga Challenge

- Si-based light sources
 - Electrically pumped
 - Lasers, LEDs
- Bulk Si indirect bandgap
 - □ e-h recombination
 - Phonon mediated
 - Slow
 - Competing processes
 - Auger process
 - Free carrier absorption

1) Light Source

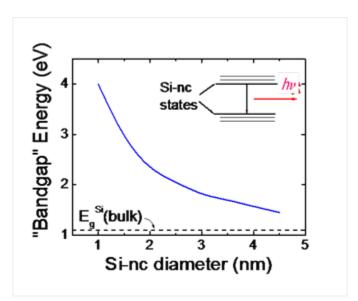


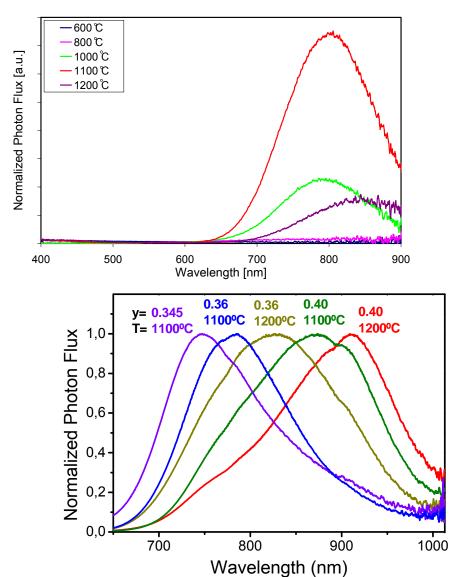




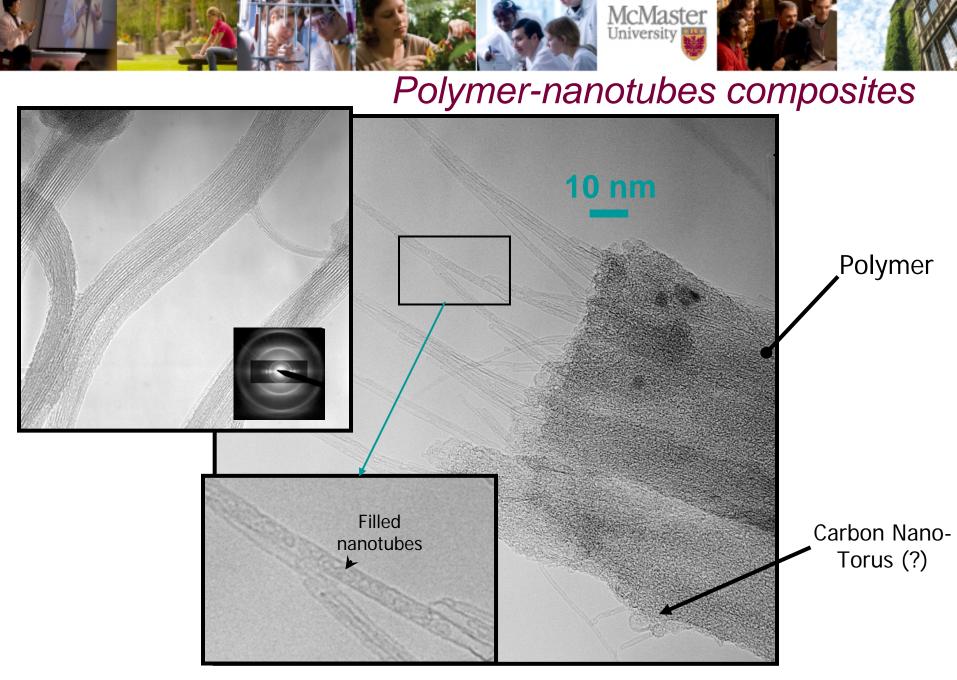
Si-ncs: Photoluminescence

- UV excited PL
 - HeCd Laser
 - 325 nm excitation
 - SRSO Samples
 - PL in the NIR





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